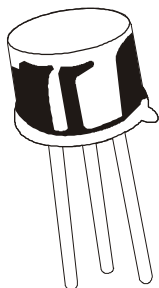


NPN SILICON PLANAR SWITCHING TRANSISTORS

2N2218A
2N2219A
TO-39



Switching And Linear Application DC And VHF Amplifier Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	2N2218A,19A	UNIT
Collector -Emitter Voltage	VCEO	40	V
Collector -Base Voltage	VCBO	75	V
Emitter -Base Voltage	VEBO	6.0	V
Collector Current Continuous	IC	800	mA
Power Dissipation @Ta=25 degC	PD	800	mW
Derate Above 25deg C		4.57	mW/deg C
@ Tc=25 degC	PD	3.0	W
Derate Above 25deg C		17.1	mW/deg C
Operating And Storage Junction Temperature Range	Tj, Tstg	-65 to +200	deg C

ELECTRICAL CHARACTERISTICS (Ta=25 deg C Unless Otherwise Specified)

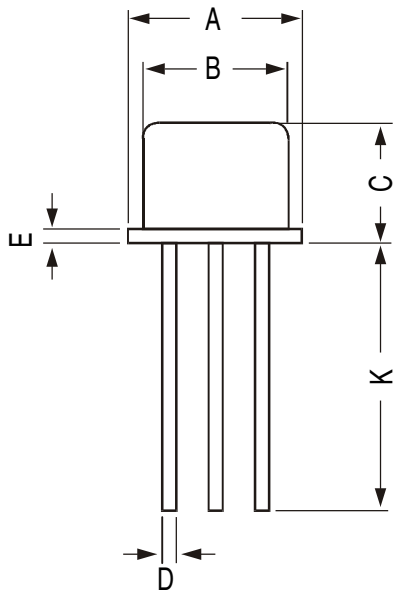
DESCRIPTION	SYMBOL	TEST CONDITION	VALUE		UNIT
			MIN	MAX	
Collector -Emitter Voltage	VCEO	IC=10mA, IB=0	40	-	V
Collector -Base Voltage	VCBO	IC=10uA, IE=0	75	-	V
Emitter-Base Voltage	VEBO	IE=10uA, IC=0	6.0	-	V
Collector-Cut off Current	ICBO	VCB=60V, IE=0	-	10	nA
Emitter-Cut off Current	ICEX	Ta=150 deg C			
		VCB=60V, IE=0	-	10	uA
		VCE=60V, VEB=3V	-	10	nA
Base-Cut off Current	IEBO	VEB=3V, IC=0	-	10	nA
Collector Emitter Saturation Voltage	VCE(Sat)*	IC=150mA, IB=15mA	-	0.3	V
		IC=500mA, IB=50mA		1.0	V
		IC=150mA, IB=15mA	-	0.6-1.2	V
Base Emitter Saturation Voltage	VBE(Sat) *	IC=150mA, IB=15mA	-	0.6-1.2	V
		IC=500mA, IB=50mA	-	2.0	V

ELECTRICAL CHARACTERISTICS (Ta=25 deg C Unless Otherwise Specified) 2N2218A to 2N2219A

DESCRIPTION	SYMBOL	TEST CONDITION	2218A	2219A	UNIT
DC Current Gain	hFE	IC=0.1mA, VCE=10V	>20	>35	
		IC=1mA, VCE=10V	>25	>50	
		IC=10mA, VCE=10V	>35	>75	
		Ta=55 deg C			
		IC=10mA, VCE=10V	>15	>35	
		IC=150mA, VCE=10V	40-120	100-300	
		IC=150mA, VCE=1V	>20	>50	
DYNAMIC CHARACTERISTICS	Small Signal Current Gain	ALL f=1kHz			
		IC=1mA, VCE=10V	30-150	50-300	
		IC=10mA, VCE=10V	50-300	75-375	
		IC=1mA, VCE=10V	1.0-3.5	2.0-8.0	kohms
		IC=10mA, VCE=10V	0.2-1.0	0.25-1.25	
		IC=1mA, VCE=10V	<5.0	<8.0	x10-4
		IC=10mA, VCE=10V	<2.5	<4.0	
Out put Admittance	hoe	IC=1mA, VCE=10V	3.0-15	5.0-35	umhos
		IC=10mA, VCE=10V	10-100	25-200	
		IC=10mA, VCE=10V	10-100	25-200	
Collector Base Time Constant	rb'Cc	IE=20mA, VCB=20V	<150	<150	ps
Real Part Common-Emitter High Frequency Input Impedance	Re(hie)	f=31.8MHz			
		IC=20mA, VCE=20V	<60	<60	ohms
Noise Figure	NF	f=300MHz			
DYNAMIC CHARACTERISTICS	Transistors Frequency	IC=100uA, VCE=10V	-	<4.0	dB
		Rs=1kohms, f=1kHz			
Out-Put Capacitance	Cob	IC=20mA, VCE=20V	>250	>300	MHz
		f=100MHz			
		VCB=10V, IE=0	<8.0	<8.0	pF
Input Capacitance	Cib	f=100kHz			
		VEB=0.5V, IC=0	<25	<25	pF
SWITCHING Time	td	f=100kHz			
		IC=150mA, IB1=15mA		<10	ns
Delay time	tr	VCC=30V, VBE=0.5V	-	<25	ns
Rise time					
Storage time	ts	IC=150mA, IB1=		<225	ns
Fall time	tf	IB2=15mA, VCC=30V	-	<60	ns

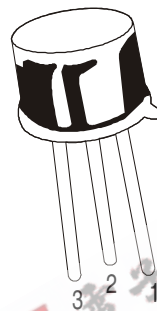
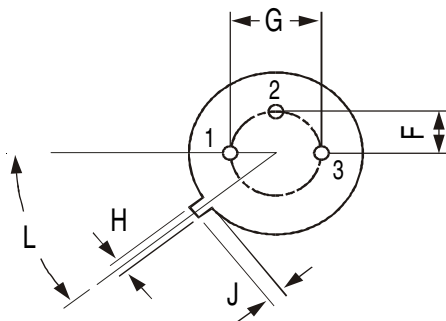
*Pulse Condition: Pulse Width=300us, Duty Cycle=2%

TO-39 Metal Can Package



All dimensions are in mm

DIM	MIN	MAX
A	8.50	9.39
B	7.74	8.50
C	6.09	6.60
D	0.40	0.53
E	—	0.88
F	2.41	2.66
G	4.82	5.33
H	0.71	0.86
J	0.73	1.02
K	12.70	—
L	42 DEG	48 DEG



PIN CONFIGURATION

1. EMITTER
2. BASE
3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20.0K	17" x 15" x 13.5"	32.0K	40 kgs

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